

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	William G. America	Conf. No.:	3775
Serial No.:	10/709,776	Art Unit:	2811
Filed:	05/27/2004	Examiner:	Im, Junghwa M.
		Docket No.:	FIS920040083US1 (IBMF-0058)
Title:	SEMICONDUCTOR DEVICE FORMED BY IN-SITU MODIFICATION OF DIELECTRIC LAYER AND RELATED METHODS		

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Sir:

I. INTRODUCTORY COMMENTS

This paper is being filed in response to the non-final Office Action dated December 1, 2008. Please amend the above-referenced patent application as follows:

The Amendments to the Claims begins on page 2 of this paper.

Remarks begin on page 4 of this paper.

The Conclusion appears at page 7 of this paper.